# NSN 5961-00-491-1439

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Inclosure Material:

Metal

**Overall Length:** 

0.460 inches

# **Overall Diameter:**

0.415 inches

Mounting Facility Quantity:

1

### Internal Configuration:

Junction contact

Internal Junction Configuration:

Npn

#### **Mounting Method:**

Threaded stud

#### Features Provided:

#### Hermetically sealed case

**Overall Width Across Flats:** 

0.687 inches

## Thread Size:

0.250 inches

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

100.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 6.0

breakdown voltage, emitter-to-base, collector open

#### **Current Rating Per Characteristic:**

Between 3.00 amperes source cutoff current and 10.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

666.0 milliwatts small-signal input power, common-collector

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

# **Thread Series Designator:**

Unf

# Terminal Type And Quantity:

1 threaded stud and 3 tab, solder lug

Shelf Life:

N/a

# Unit Of Measure:

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#### Demilitarization:

No

## Fiig:

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